

# F1T1G - F1T7G

1.0 AMP. Glass Passivated Fast Recovery Rectifiers

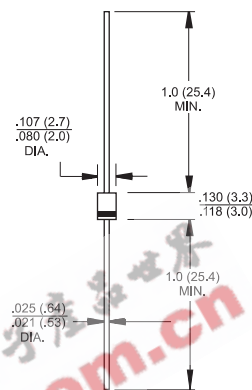
**TS-1**

## Features

- ✧ Glass passivated chip junction.
- ✧ High efficiency, Low VF
- ✧ High current capability
- ✧ High reliability
- ✧ High surge current capability
- ✧ Low power loss

## Mechanical Data

- ✧ Cases: Molded plastic
- ✧ Epoxy: UL 94V-0 rate flame retardant
- ✧ Lead: Pure tin plated, Lead free., solderable per MIL-STD-202, Method 208 guaranteed
- ✧ Polarity: Color band denotes cathode end
- ✧ High temperature soldering guaranteed: 260 °C /10 seconds/.375", (9.5mm) lead lengths at 5 lbs., (2.3kg) tension
- ✧ Mounting position: Any
- ✧ Weight: 0.20 gram



Dimensions in inches and (millimeters)

## Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	F1T 1G	F1T 2G	F1T 3G	F1T 4G	F1T 5G	F1T 6G	F1T 7G	Units
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375" (9.5mm) Lead Length @ $T_A = 55^\circ\text{C}$	$I_{(AV)}$	1.0							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method )	$I_{FSM}$	30							A
Maximum Instantaneous Forward Voltage @ 1.0A	$V_F$	1.3							V
Maximum DC Reverse Current @ $T_A=25^\circ\text{C}$ at Rated DC Blocking Voltage @ $T_A=125^\circ\text{C}$	$I_R$	5.0 150							 uA
Maximum Reverse Recovery Time ( Note 1 )	$T_{rr}$	150				250	500		nS
Typical Junction Capacitance ( Note 2 )	$C_j$	15							pF
Typical Thermal Resistance (Note 3)	$R_{\theta JA}$	90							$^\circ\text{C/W}$
Operating Temperature Range $T_J$	$T_J$	-65 to +150							$^\circ\text{C}$
Storage Temperature Range $T_{STG}$	$T_{STG}$	-65 to +150							$^\circ\text{C}$

- Notes:
1. Reverse Recovery Test Conditions:  $I_F=0.5\text{A}$ ,  $I_R=1.0\text{A}$ ,  $I_{RR}=0.25\text{A}$
  2. Measured at 1 MHz and Applied Reverse Voltage of 4. 0 Volts D.C.
  3. Mount on Cu-Pad Size 5mm x 5mm on P.C.B.

## RATINGS AND CHARACTERISTIC CURVES (F1T1G THRU F1T7G)

FIG.1- MAXIMUM FORWARD CURRENT DERATING CURVE

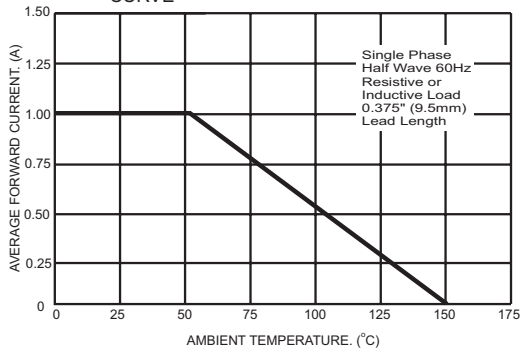


FIG.2- TYPICAL REVERSE CHARACTERISTICS PER LEG

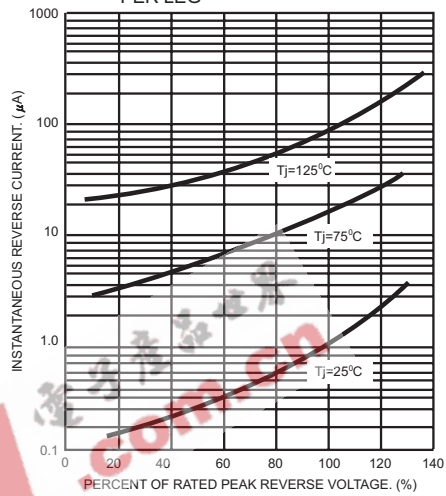


FIG.3- MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

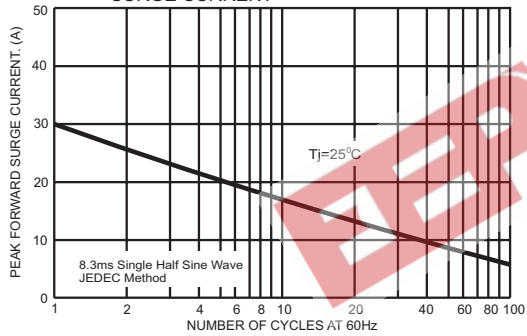


FIG.5- TYPICAL FORWARD CHARACTERISTICS

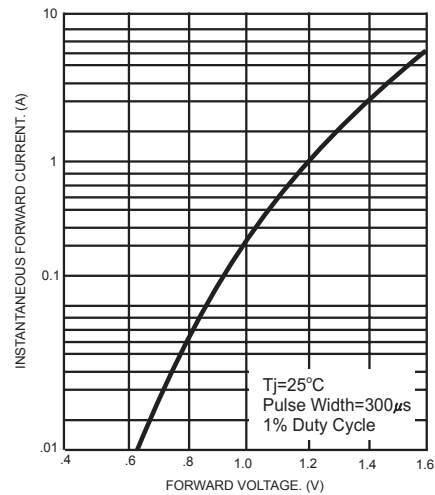


FIG.4- TYPICAL JUNCTION CAPACITANCE

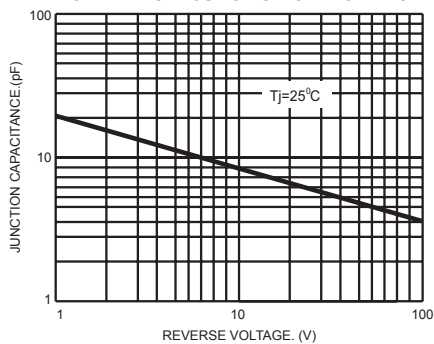


FIG.6- REVERSE RECOVERY TIME CHARACTERISTIC AND TEST CIRCUIT DIAGRAM

